## NSN 5962-01-370-0998

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View Online at https://aerobasegroup.com/nsn/5962-01-370-0998 **Body Length:** 0.830 inches **Body Width:** Between 0.430 inches and 0.488 inches **Body Height:** Between 0.090 inches and 0.120 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and hermetically sealed and bidirectional and erasable and electrostatic sensitive and programmable and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 27 input **Current Rating Per Characteristic:** 80.00 milliamperes forward current, nonrepetitive, peak total value minor **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 6.0 volts power source **Memory Device Type: Eeprom Hybrid Technology Type:** Monolithic **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 32 flat leads Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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